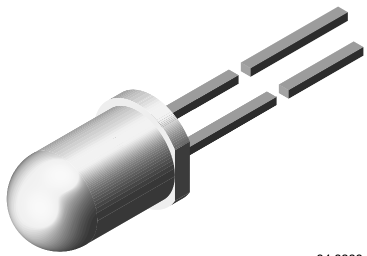
High Speed Infrared Emitting Diode, 850 nm, GaAlAs Double Hetero



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FEATURES

- Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): ∅ 5
- Peak wavelength: λ_p = 850 nm
- High reliability
- High radiant power
- High radiant intensity
- Angle of half intensity: φ = ± 18°
- Low forward voltage
- Suitable for high pulse current operation
- High modulation bandwidth: f_c = 18 MHz
- Good spectral matching with CMOS cameras
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

Pb
e3
RoHS COMPLIANT
HALOGEN FREE

DESCRIPTION

TSHG6410 is an infrared, 850 nm emitting diode in GaAlAs double hetero (DH) technology with high radiant power and high speed, molded in a clear, untinted plastic package.

APPLICATIONS

- Infrared radiation source for operation with CMOS cameras
- High speed IR data transmission

PRODUCT SUMMARY

COMPONENT	I_e (mW/sr)	φ (deg)	λ_p (nm)	t_r (ns)
TSHG6410	90	± 18	850	20

Note
Test conditions see table “Basic Characteristics”

ORDERING INFORMATION

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
TSHG6410	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾

Note
MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_R	5	V
Forward current		I_F	100	mA
Peak forward current	t_p/T = 0.5, t_p = 100 µs	I_{FM}	200	mA
Surge forward current	t_p = 100 µs	I_{FSM}	1	A
Power dissipation		P_V	180	mW
Junction temperature		T_j	100	°C
Operating temperature range		T_{amb}	- 40 to + 85	°C
Storage temperature range		T_{stg}	- 40 to + 100	°C
Soldering temperature	t ≤ 5 s, 2 mm from case	T_{sd}	260	°C
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R_{thJA}	230	K/W

Note
T_{amb} = 25 °C, unless otherwise specified

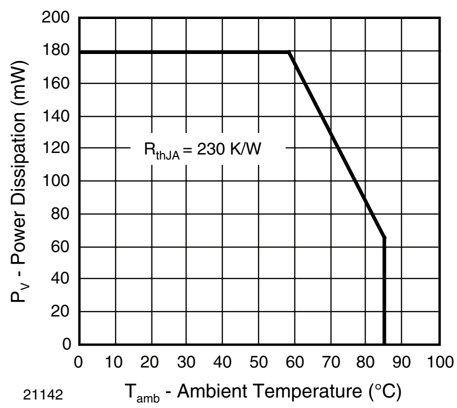

Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

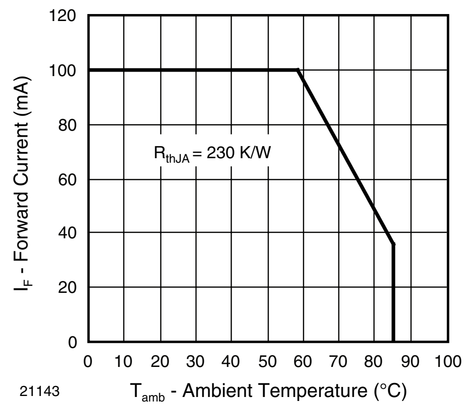

Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I_F = 100 mA, t_p = 20 ms	V_F		1.5	1.8	V
	I_F = 1 A, t_p = 100 µs	V_F		2.3		V
Temperature coefficient of V_F	I_F = 1 mA	TK_{VF}		- 1.8		mV/K
Reverse current	V_R = 5 V	I_R			10	µA
Junction capacitance	V_R = 0 V, f = 1 MHz, E = 0	C_j		125		pF
Radiant intensity	I_F = 100 mA, t_p = 20 ms	I_e	45	90	135	mW/sr
	I_F = 1 A, t_p = 100 µs	I_e		900		mW/sr
Radiant power	I_F = 100 mA, t_p = 20 ms	ϕ_e		55		mW
Temperature coefficient of ϕ_e	I_F = 100 mA	$TK\phi_e$		- 0.35		%/K
Angle of half intensity		φ		± 18		deg
Peak wavelength	I_F = 100 mA	λ_p	820	850	880	nm
Spectral bandwidth	I_F = 100 mA	$\Delta\lambda$		40		nm
Temperature coefficient of λ_p	I_F = 100 mA	$TK\lambda_p$		0.25		nm/K
Rise time	I_F = 100 mA	t_r		20		ns
Fall time	I_F = 100 mA	t_f		13		ns
Cut-off frequency	I_{DC} = 70 mA, I_{AC} = 30 mA pp	f_c		18		MHz
Virtual source diameter		d		2.1		mm

Note

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BASIC CHARACTERISTICS

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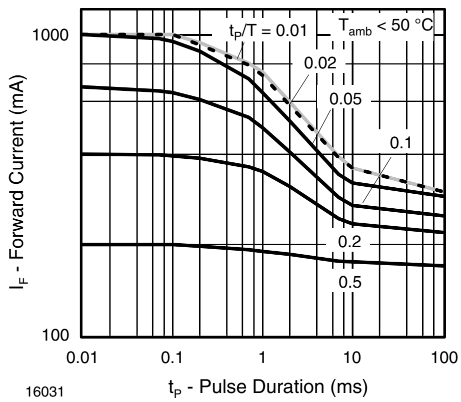


Fig. 3 - Pulse Forward Current vs. Pulse Duration

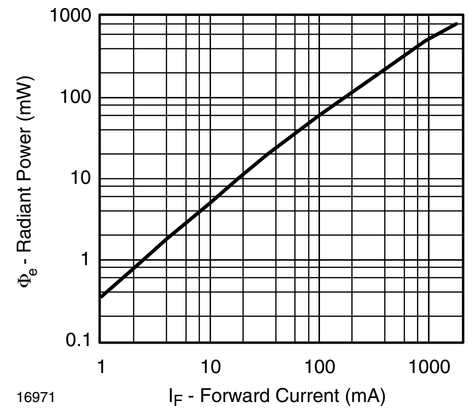


Fig. 6 - Radiant Power vs. Forward Current

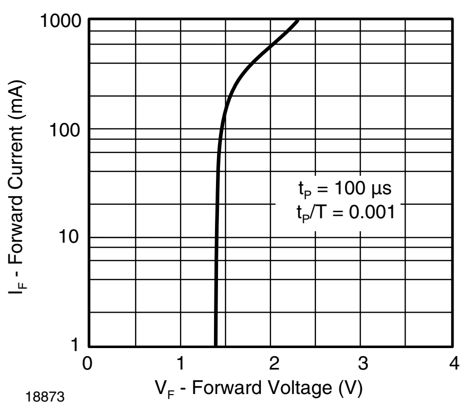


Fig. 4 - Forward Current vs. Forward Voltage

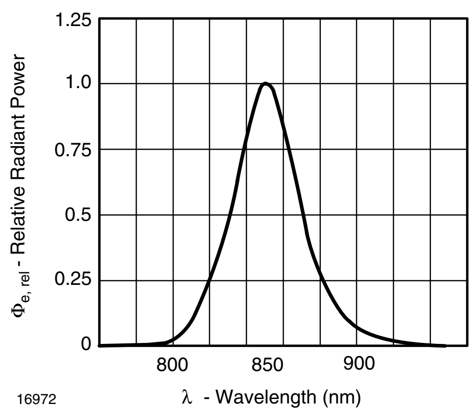


Fig. 7 - Relative Radiant Power vs. Wavelength

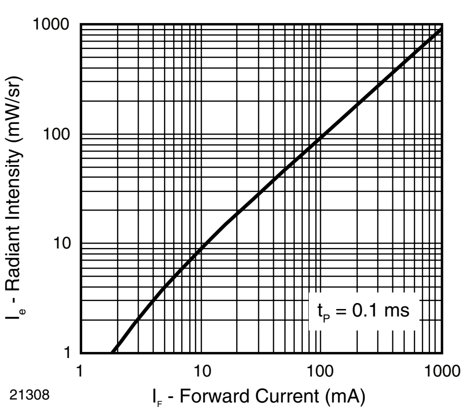


Fig. 5 - Radiant Intensity vs. Forward Current

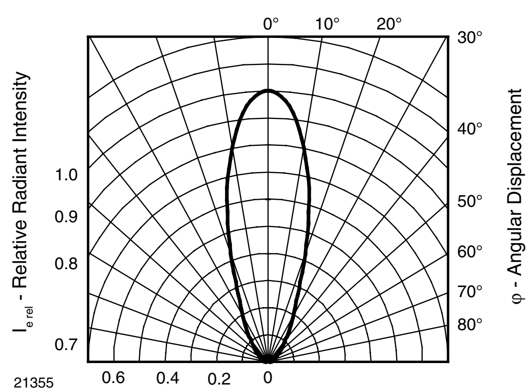
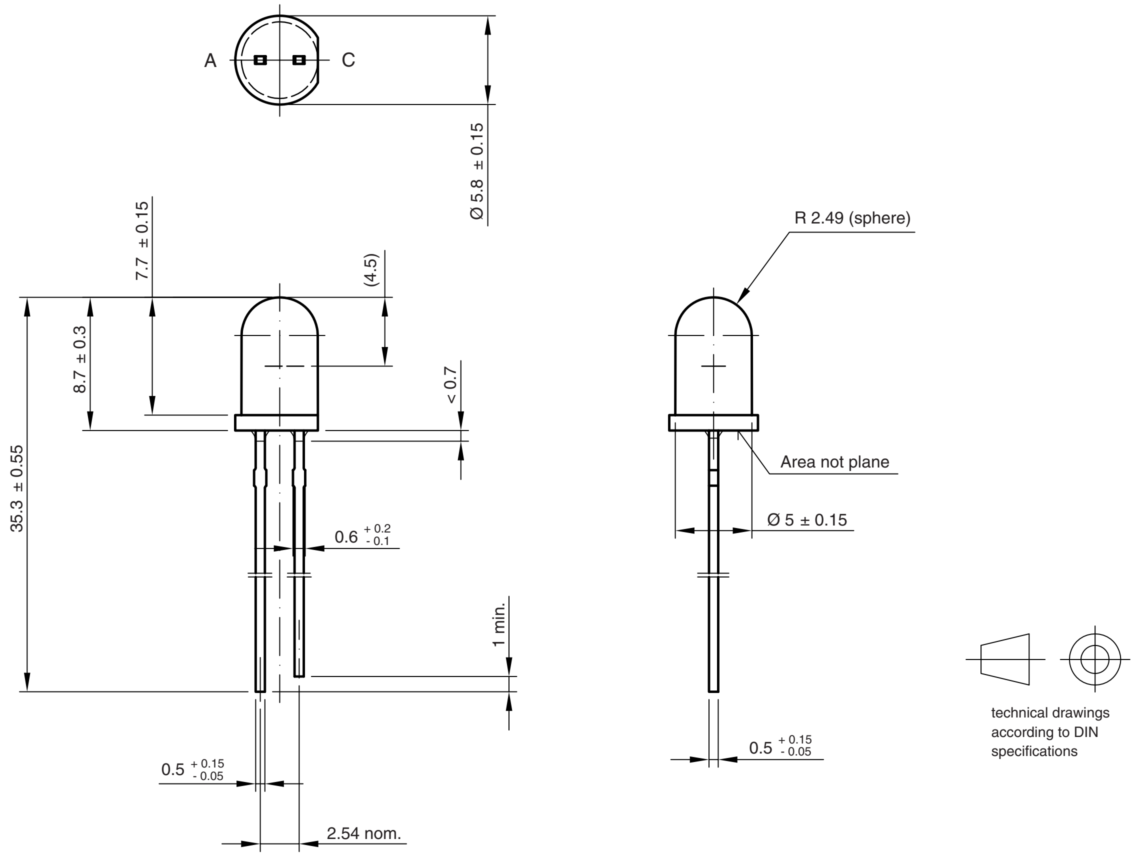


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

PACKAGE DIMENSIONS in millimeters



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